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To:	Examiner: Pham Long	From:	Leslie S. Szivos, Ph.D.
Fax:	703 872-9306	Pages:	Including Cover Sheet
Phone:		Date:	2/23/2005
Re:	U.S. Appl. Serial No. 10/662,900 Filed: September 15, 2003 Docket No.: YOR920030218US1 (16714)		
CC:			

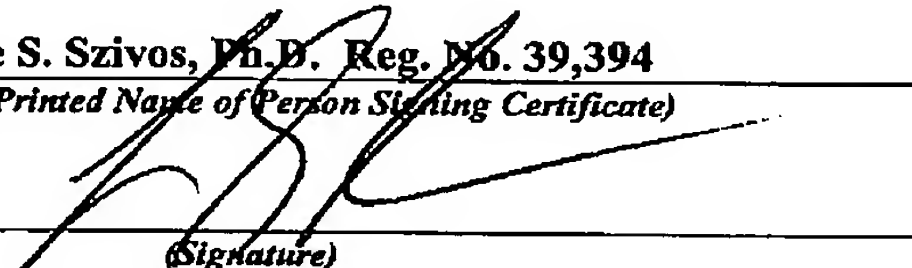
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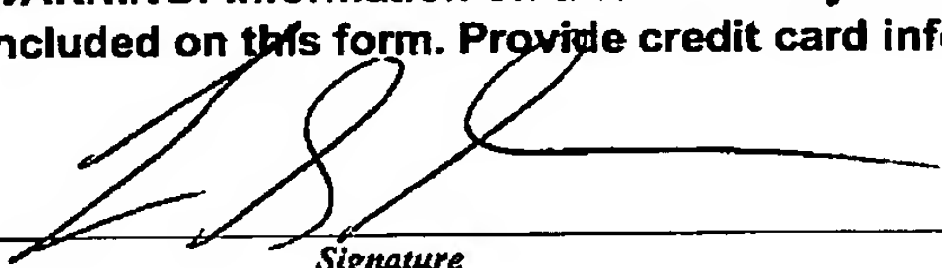
Attached hereto is:

1. Response Under 37 C.F. R. §1.111 & §1.143
2. Amendment Transmittal (in duplicate)
3. Certificate of Facsimile

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CERTIFICATE OF TRANSMISSION BY FACSIMILE (37 CFR 1.8)			Docket No.
Applicant(s): Cyril Cabral, Jr., et al.			YOR920030218US1 (16714)
Application No. 10/662,900	Filing Date September 15, 2003	Examiner Pham Long	Group Art Unit 2814
Invention: REDUCTION OF SILICIDE FORMATION TEMPERATURE ON SiGe CONTAINING SUBSTRATES			
<p>I hereby certify that this <u>Response Under 37 C.F.R. §1.111 & §1.143</u> <i>(Identify type of correspondence)</i> is being facsimile transmitted to the United States Patent and Trademark Office (Fax. No. <u>703 872-9306</u>) on <u>February 23, 2005</u> <i>(Date)</i></p> <p style="text-align: center;"><u>Leslie S. Szivos, Ph.D. Reg. No. 39,394</u> <i>(Typed or Printed Name of Person Signing Certificate)</i>  <i>(Signature)</i></p> <p style="text-align: center;">Note: Each paper must have its own certificate of mailing.</p>			

TRANSMITTAL LETTER (General - Patent Pending)				Docket No. YOR920030218US1 (16714)	
In Re Application Of: Cyril Cabral, Jr., et al.					
Application No. 10/662,900	Filing Date 9/15/2003	Examiner Long Pham	Customer No. 23389	Group Art Unit 2814	Confirmation No. 1278
Title: REDUCTION OF SILICIDE FORMATION TEMPERATURE ON SiGe CONTAINING SUBSTRATES					
COMMISSIONER FOR PATENTS:					
Transmitted herewith is: Response Under 37 C.F.R. §1.111 & §1.143					
In the above identified application.					
<input checked="" type="checkbox"/> No additional fee is required.					
<input type="checkbox"/> A check in the amount of _____ is attached.					
<input checked="" type="checkbox"/> The Director is hereby authorized to charge and credit Deposit Account No. 50-0510/IBM as described below.					
<input type="checkbox"/> Charge the amount of _____					
<input checked="" type="checkbox"/> Credit any overpayment.					
<input checked="" type="checkbox"/> Charge any additional fee required.					
<input type="checkbox"/> Payment by credit card. Form PTO-2038 is attached.					
WARNING: Information on this form may become public. Credit card information should not be included on this form. Provide credit card information and authorization on PTO-2038.					
 Signature			Dated: February 23, 2005		
Leslie S. Szivos, Ph.D. Registration No. 39,394					
CC:			<div style="border-bottom: 1px solid black; margin-bottom: 5px;">I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as first class mail in an envelope addressed to the "Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450" [37 CFR 1.8(a)] on:</div> <div style="border-bottom: 1px solid black; margin-bottom: 5px; text-align: center;">(Date)</div> <div style="border-bottom: 1px solid black; margin-bottom: 5px; text-align: center;">Signature of Person Mailing Correspondence</div> <div style="border-bottom: 1px solid black; margin-bottom: 5px; text-align: center;">Typed or Printed Name of Person Mailing Correspondence</div>		

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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s): Cyril Cabral, Jr., et al.

Examiner: Long Pham

Serial No: 10/662,900

Art Unit: 2814

Filed: September 15, 2003

Docket: YOR920030218US1 (16714)

Dated: February 23, 2005

For: REDUCTION OF SILICIDE FORMATION TEMPERATURE ON SiGe CONTAINING SUBSTRATES

Confirmation No: 1278

Mail Stop: Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

RESPONSE UNDER 37 C.F.R. §§1.111 AND 1.143

Sir:

In response to the Office Action dated January 25, 2005, applicants provisionally elect, without traverse, the subject matter of Group I, i.e., Claims 1-17 for continued prosecution in the above-identified patent application.

CERTIFICATION OF FACSIMILE TRANSMISSION

I hereby certify that this paper is being facsimile transmitted to the Patent and Trademark Office on the date shown below.

Dated: February 23, 2005


Leslie S. Szivos, Ph.D.